



**Absolute Maximum Ratings** at  $T_j=25$  unless otherwise noted

Parameter	Symbol	Value	Unit
Drain-source voltage	$V_{DS}$	650	V
Gate-source voltage	$V_{GS}$	$\pm 30$	V
Continuous drain current <sup>1)</sup> , $T_C=25$ °C	$I_D$	11	A
Continuous drain current <sup>1)</sup> , $T_C=100$ °C		7	
Pulsed drain current <sup>2)</sup> , $T_C=25$ °C	$I_{D, pulse}$	33	A
Continuous diode forward current <sup>1)</sup> , $T_C=25$ °C	$I_S$	11	A
Diode pulsed current <sup>2)</sup> , $T_C=25$ °C	$I_{S, pulse}$	33	A
Power dissipation <sup>3)</sup> , $T_C=25$ °C	$P_D$	31	W
Single pulsed avalanche energy <sup>5)</sup>	$E_{AS}$	249	mJ
MOSFET dv/dt ruggedness, $V_{DS}$	dv/dt	50	V/ns
Reverse diode dv/dt, $V_{DS}$	dv/dt	15	V/ns
Operation and storage temperature	$T_{stg}, T_j$	-55 to 150	°C

**Thermal Characteristics**

Parameter	Symbol	Value	Unit
Thermal resistance, junction-case	R	4.03	°C/W
Thermal resistance, junction-ambient <sup>4)</sup>	R	62.5	°C/W

**Electrical Characteristics** at  $T_j=25$  unless otherwise specified

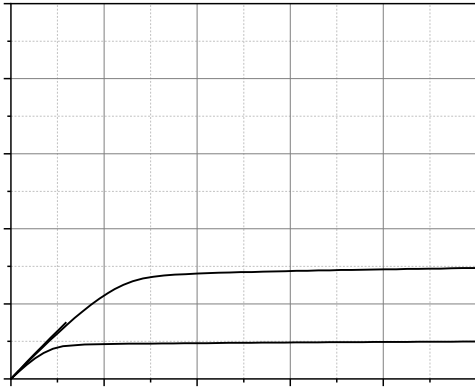
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test condition
Drain-source breakdown voltage	$BV_{DSS}$	650			V	$V_{GS}=0$ V, $I_D=250$ A
		700				$V_{GS}=0$ V, $I_D$ , $T_j=150$ °C
Gate threshold voltage	$V_{GS(th)}$	2.9		3.9	V	$V_{DS}=V_{GS}$ , $I_D=250$ A
Drain-source on-state resistance	$R_{DS(on)}$		0.3	0.38		$V_{GS}=10$ V, $I_D=7.5$ A
			0.76			$V_{GS}=10$ V, $I_D=7.5$ A, $T_j=150$ °C

Gate-source  
leakage: 11 2181. reW

**Dynamic Characteristics**

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test condition
Input capacitance	$C_{iss}$		776		pF	$V_{GS}=0\text{ V}$ , $V_{DS}=50\text{ V}$ , kHz
Output capacitance	$C_{oss}$		58.5		pF	
Reverse transfer capacitance	$C_{rss}$		0.8		pF	

### Electrical Characteristics Diagrams



**Figure 1. Typ. output characteristics**

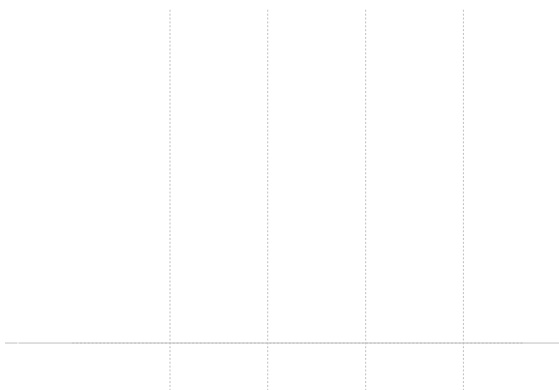


**Figure 2. Typ. transfer characteristics**



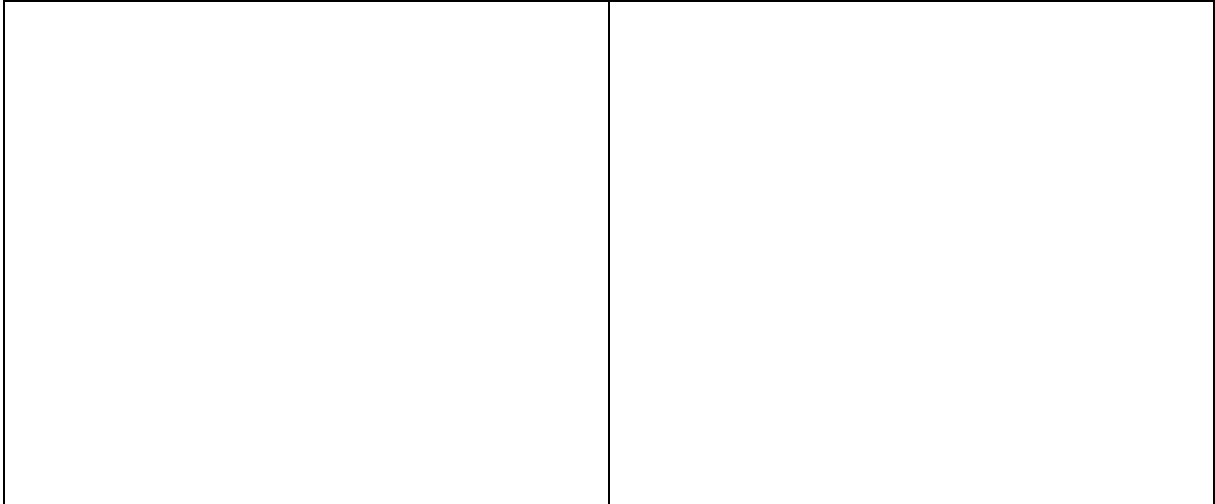
**Figure 3. Typ. capacitances**

**Figure 4. Typ. gate charge**



**Figure 5. Drain-source breakdown voltage**

**Figure 6. Drain-source on-state resistance**



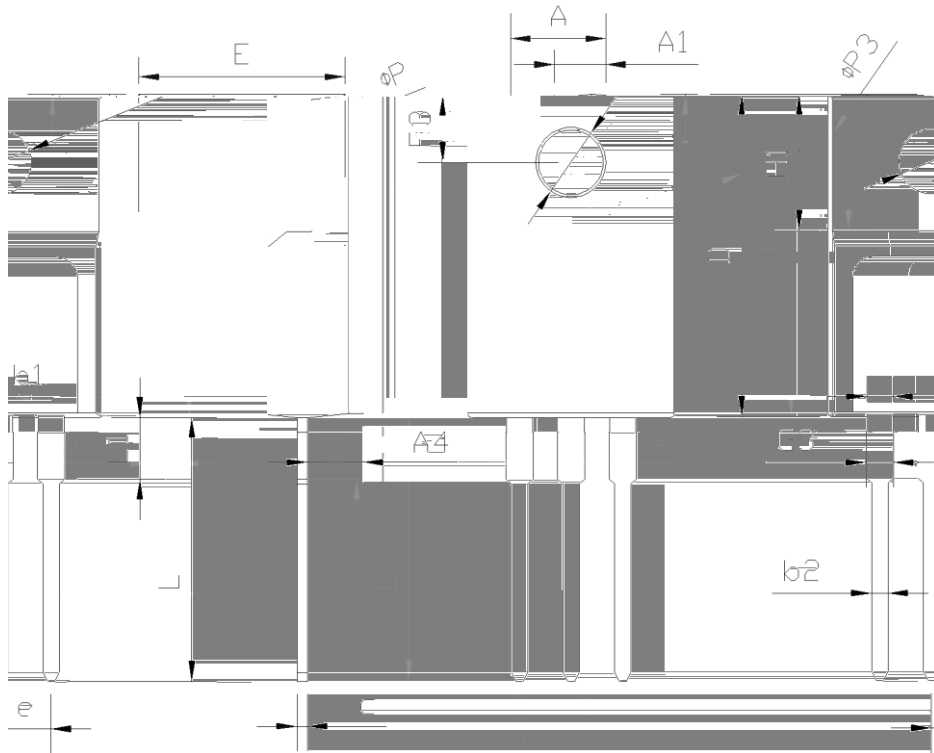
**Figure 7. Threshold voltage**

**Figure**





**Package Information**

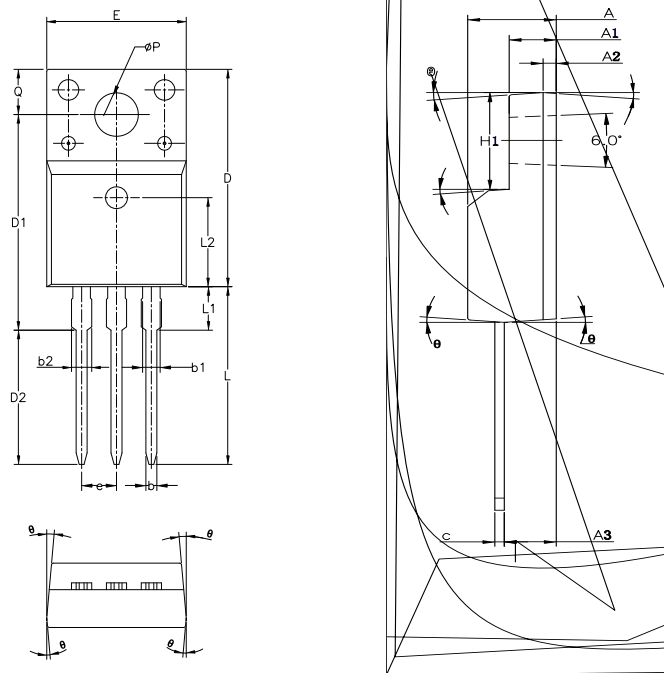


Symbol	mm		
	Min	Nom	Max
E	9.96	10.16	10.36
A	4.50	4.70	4.90
A1	2.34	2.54	2.74
A4	2.56	2.76	2.96
c	0.40	0.50	0.65
D	15.57	15.87	16.17
H1	6.70 REF		
e	2.54 BSC		
L	12.68	12.98	13.28
L1	2.88	3.03	3.18
	3.03	3.18	3.38
	3.15	3.45	3.65
F3	3.15	3.30	3.45
G3	1.25	1.35	1.55
b1	1.18	1.28	1.43
b2	0.70	0.80	0.95

Version 1: TO220F-C package outline dimension



**Package Information**



Symbol	mm		
	Min	Nom	Max
A	4.50	4.70	4.83
A1	2.34	2.54	2.74
A2	0.70 REF		
A3	2.56	2.76	2.93
b	0.70	-	0.90
b1	1.18	-	1.38
b2	-	-	1.47
c	0.45	0.50	0.60
D	15.67	15.87	16.07
D1	15.55	15.75	15.95
D2	9.60	9.80	10.00
E	9.96	10.16	10.36
e	2.54 BSC		
H1	6.48	6.68	6.88
L	12.68	12.98	13.28
L1	-	-	3.50
L2	6.50 REF		
	3.08	3.18	3.28
Q	3.20	-	3.40
	1°	3°	5°

Version 2: TO220F-J package outline dimension

### Ordering Information

Package Type	Units/ Tube	Tubes/ Inner Box	Units/ Inner Box	Inner Boxes/ Carton Box	Units/ Carton Box
TO220F-C	50	20	1000	6	6000
TO220F-J	50	20	1000	5	5000

### Product Information

<b>Product</b>	<b>Package</b>	<b>Pb Free</b>	<b>RoHS</b>	<b>Halogen Free</b>
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